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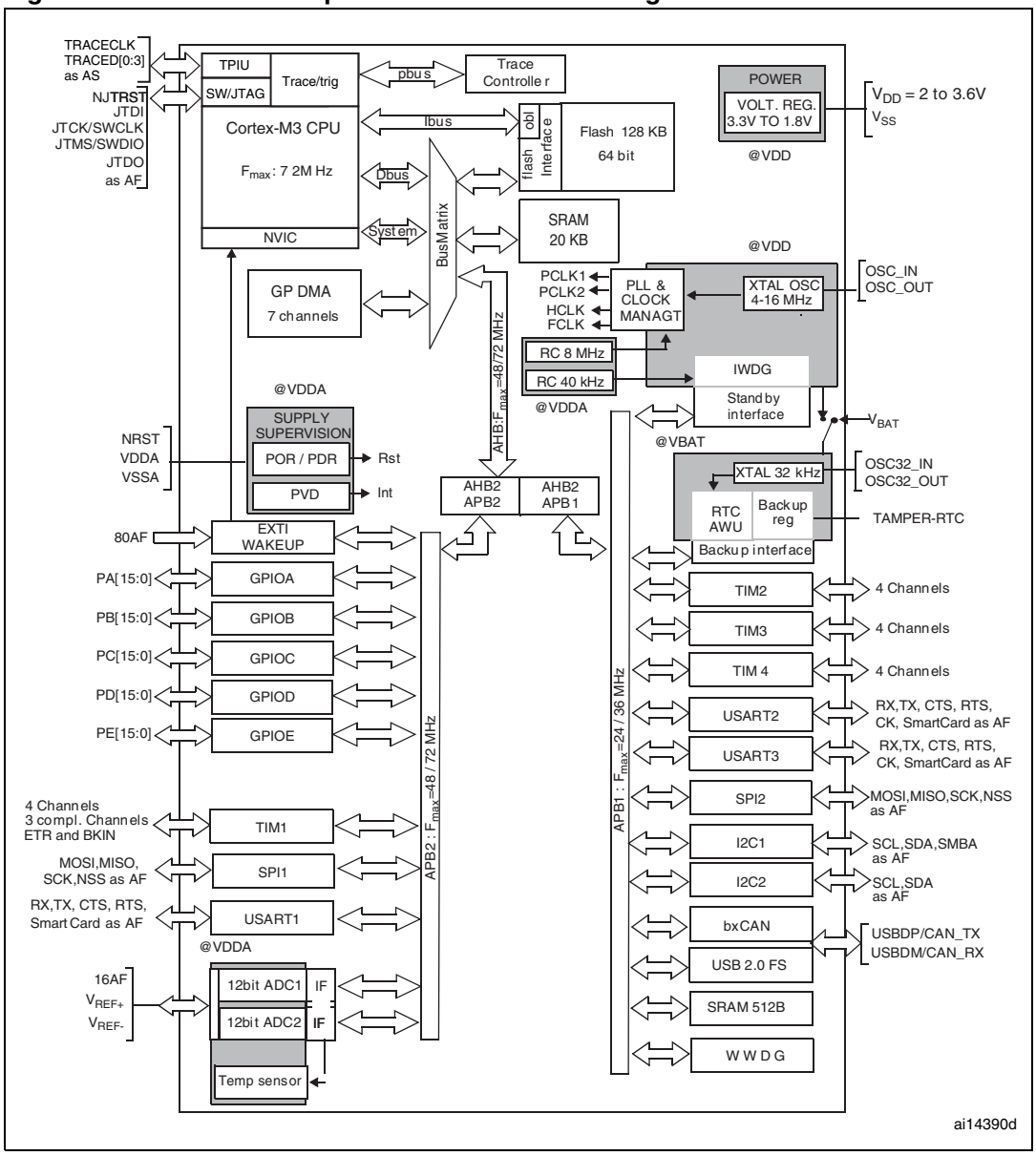
"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M3
Core Size	32-Bit Single-Core
Speed	72MHz
Connectivity	CANbus, I²C, IrDA, LINbus, SPI, UART/USART, USB
Peripherals	DMA, Motor Control PWM, PDR, POR, PVD, PWM, Temp Sensor, WDT
Number of I/O	26
Program Memory Size	64KB (64K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	20K x 8
Voltage - Supply (Vcc/Vdd)	2V ~ 3.6V
Data Converters	A/D 10x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	36-VFQFN Exposed Pad
Supplier Device Package	36-VFQFPN (6x6)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32f103t8u7

Figure 1. STM32F103xx performance line block diagram



1. T_A = –40 °C to +105 °C (junction temperature up to 125 °C).
2. AF = alternate function on I/O port pin.

Table 5. Medium-density STM32F103xx pin definitions

Pins						Pin name	Type(1)	I / O Level(2)	Main function(3) (after reset)	Alternate functions	
LFBGA100	LQFP48	TFBGA64	LQFP64	LQFP100	VFQFPN36					Default	Remap
A3	-		-	1	-	PE2	I/O	FT	PE2	TRACECK	
B3	-		-	2	-	PE3	I/O	FT	PE3	TRACED0	
C3	-		-	3	-	PE4	I/O	FT	PE4	TRACED1	
D3	-		-	4	-	PE5	I/O	FT	PE5	TRACED2	
E3	-		-	5	-	PE6	I/O	FT	PE6	TRACED3	
B2	1	B2	1	6	-	V_{BAT}	S		V_{BAT}		
A2	2	A2	2	7	-	PC13-TAMPER-RTC(4)	I/O		PC13(5)	TAMPER-RTC	
A1	3	A1	3	8	-	PC14-OSC32_IN(4)	I/O		PC14(5)	OSC32_IN	
B1	4	B1	4	9	-	PC15-OSC32_OUT(4)	I/O		PC15(5)	OSC32_OUT	
C2	-	-	-	10	-	V_{SS_5}	S		V_{SS_5}		
D2	-	-	-	11	-	V_{DD_5}	S		V_{DD_5}		
C1	5	C1	5	12	2	OSC_IN	I		OSC_IN		
D1	6	D1	6	13	3	OSC_OUT	O		OSC_OUT		
E1	7	E1	7	14	4	NRST	I/O		NRST		
F1	-	E3	8	15	-	PC0	I/O		PC0	ADC12_IN10	
F2	-	E2	9	16	-	PC1	I/O		PC1	ADC12_IN11	
E2	-	F2	10	17	-	PC2	I/O		PC2	ADC12_IN12	
F3	-	-(6)	11	18	-	PC3	I/O		PC3	ADC12_IN13	
G1	8	F1	12	19	5	V_{SSA}	S		V_{SSA}		
H1	-	-	-	20	-	V_{REF-}	S		V_{REF-}		
J1	-	G1(6)	-	21	-	V_{REF+}	S		V_{REF+}		
K1	9	H1	13	22	6	V_{DDA}	S		V_{DDA}		
G2	10	G2	14	23	7	PA0-WKUP	I/O		PA0	WKUP/ USART2_CTS(7)/ ADC12_IN0/ TIM2_CH1_ETR(7)	
H2	11	H2	15	24	8	PA1	I/O		PA1	USART2_RTS(7)/ ADC12_IN1/ TIM2_CH2(7)	
J2	12	F3	16	25	9	PA2	I/O		PA2	USART2_TX(7)/ ADC12_IN2/ TIM2_CH3(7)	

Table 5. Medium-density STM32F103xx pin definitions (continued)

Pins						Pin name	Type(1)	I / O Level(2)	Main function(3) (after reset)	Alternate functions	
LFBGA100	LQFP48	TFBGA64	LQFP64	LQFP100	VFQFPN36					Default	Remap
K2	13	G3	17	26	10	PA3	I/O		PA3	USART2_RX(7)/ ADC12_IN3/ TIM2_CH4(7)	
E4	-	C2	18	27	-	V_{SS_4}	S		V_{SS_4}		
F4	-	D2	19	28	-	V_{DD_4}	S		V_{DD_4}		
G3	14	H3	20	29	11	PA4	I/O		PA4	SPI1_NSS(7)/ USART2_CK(7)/ ADC12_IN4	
H3	15	F4	21	30	12	PA5	I/O		PA5	SPI1_SCK(7)/ ADC12_IN5	
J3	16	G4	22	31	13	PA6	I/O		PA6	SPI1_MISO(7)/ ADC12_IN6/ TIM3_CH1(7)	TIM1_BKIN
K3	17	H4	23	32	14	PA7	I/O		PA7	SPI1_MOSI(7)/ ADC12_IN7/ TIM3_CH2(7)	TIM1_CH1N
G4	-	H5	24	33		PC4	I/O		PC4	ADC12_IN14	
H4	-	H6	25	34		PC5	I/O		PC5	ADC12_IN15	
J4	18	F5	26	35	15	PB0	I/O		PB0	ADC12_IN8/ TIM3_CH3(7)	TIM1_CH2N
K4	19	G5	27	36	16	PB1	I/O		PB1	ADC12_IN9/ TIM3_CH4(7)	TIM1_CH3N
G5	20	G6	28	37	17	PB2	I/O	FT	PB2/BOOT1		
H5	-	-	-	38	-	PE7	I/O	FT	PE7		TIM1_ETR
J5	-	-	-	39	-	PE8	I/O	FT	PE8		TIM1_CH1N
K5	-	-	-	40	-	PE9	I/O	FT	PE9		TIM1_CH1
G6	-	-	-	41	-	PE10	I/O	FT	PE10		TIM1_CH2N
H6	-	-	-	42	-	PE11	I/O	FT	PE11		TIM1_CH2
J6	-	-	-	43	-	PE12	I/O	FT	PE12		TIM1_CH3N
K6	-	-	-	44	-	PE13	I/O	FT	PE13		TIM1_CH3
G7	-	-	-	45	-	PE14	I/O	FT	PE14		TIM1_CH4
H7	-	-	-	46	-	PE15	I/O	FT	PE15		TIM1_BKIN
J7	21	G7	29	47	-	PB10	I/O	FT	PB10	I2C2_SCL/ USART3_TX(7)	TIM2_CH3
K7	22	H7	30	48	-	PB11	I/O	FT	PB11	I2C2_SDA/ USART3_RX(7)	TIM2_CH4
E7	23	D6	31	49	18	V_{SS_1}	S		V_{SS_1}		

Table 5. Medium-density STM32F103xx pin definitions (continued)

Pins						Pin name	Type(1)	I / O Level(2)	Main function(3) (after reset)	Alternate functions	
LFBGA100	LQFP48	TFBGA64	LQFP64	LQFP100	VFQFPN36					Default	Remap
A10	34	A8	46	72	25	PA13	I/O	FT	JTMS/SWDIO		PA13
F8	-	-	-	73	-	Not connected					
E6	35	D5	47	74	26	V_{SS_2}	S		V_{SS_2}		
F6	36	E5	48	75	27	V_{DD_2}	S		V_{DD_2}		
A9	37	A7	49	76	28	PA14	I/O	FT	JTCK/SWCLK		PA14
A8	38	A6	50	77	29	PA15	I/O	FT	JTDI		TIM2_CH1_ETR/ PA15 /SPI1_NSS
B9	-	B7	51	78		PC10	I/O	FT	PC10		USART3_TX
B8	-	B6	52	79		PC11	I/O	FT	PC11		USART3_RX
C8	-	C5	53	80		PC12	I/O	FT	PC12		USART3_CK
D8	5	C1	5	81	2	PD0	I/O	FT	OSC_IN(8)		CANRX
E8	6	D1	6	82	3	PD1	I/O	FT	OSC_OUT(8)		CANTX
B7		B5	54	83	-	PD2	I/O	FT	PD2	TIM3_ETR	
C7	-	-	-	84	-	PD3	I/O	FT	PD3		USART2_CTS
D7	-	-	-	85	-	PD4	I/O	FT	PD4		USART2_RTS
B6	-	-	-	86	-	PD5	I/O	FT	PD5		USART2_TX
C6	-	-	-	87	-	PD6	I/O	FT	PD6		USART2_RX
D6	-	-	-	88	-	PD7	I/O	FT	PD7		USART2_CK
A7	39	A5	55	89	30	PB3	I/O	FT	JTDO		TIM2_CH2 / PB3 TRACESWO SPI1_SCK
A6	40	A4	56	90	31	PB4	I/O	FT	JNTRST		TIM3_CH1/ PB4/ SPI1_MISO
C5	41	C4	57	91	32	PB5	I/O		PB5	I2C1_SMBAI	TIM3_CH2 / SPI1_MOSI
B5	42	D3	58	92	33	PB6	I/O	FT	PB6	I2C1_SCL(7)/ TIM4_CH1(7)	USART1_TX
A5	43	C3	59	93	34	PB7	I/O	FT	PB7	I2C1_SDA(7)/ TIM4_CH2(7)	USART1_RX
D5	44	B4	60	94	35	BOOT0	I		BOOT0		
B4	45	B3	61	95	-	PB8	I/O	FT	PB8	TIM4_CH3(7)	I2C1_SCL / CANRX
A4	46	A3	62	96	-	PB9	I/O	FT	PB9	TIM4_CH4(7)	I2C1_SDA/ CANTX

5 Electrical characteristics

5.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to V_{SS}.

5.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at T_A = 25 °C and T_A = $T_A$max (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean±3Σ).

5.1.2 Typical values

Unless otherwise specified, typical data are based on T_A = 25 °C, V_{DD} = 3.3 V (for the 2 V ≤ V_{DD} ≤ 3.6 V voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean±2Σ).

5.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

5.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in *Figure 10*.

5.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in *Figure 11*.

Figure 14. Typical current consumption in Run mode versus frequency (at 3.6 V) - code with data processing running from RAM, peripherals enabled

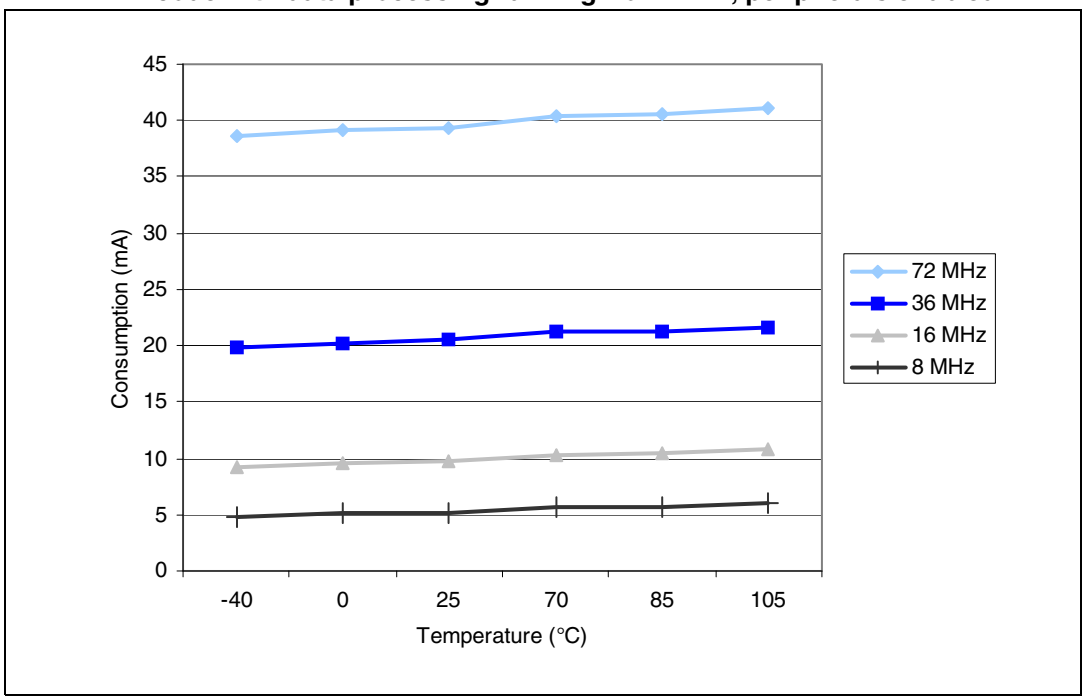


Figure 15. Typical current consumption in Run mode versus frequency (at 3.6 V) - code with data processing running from RAM, peripherals disabled

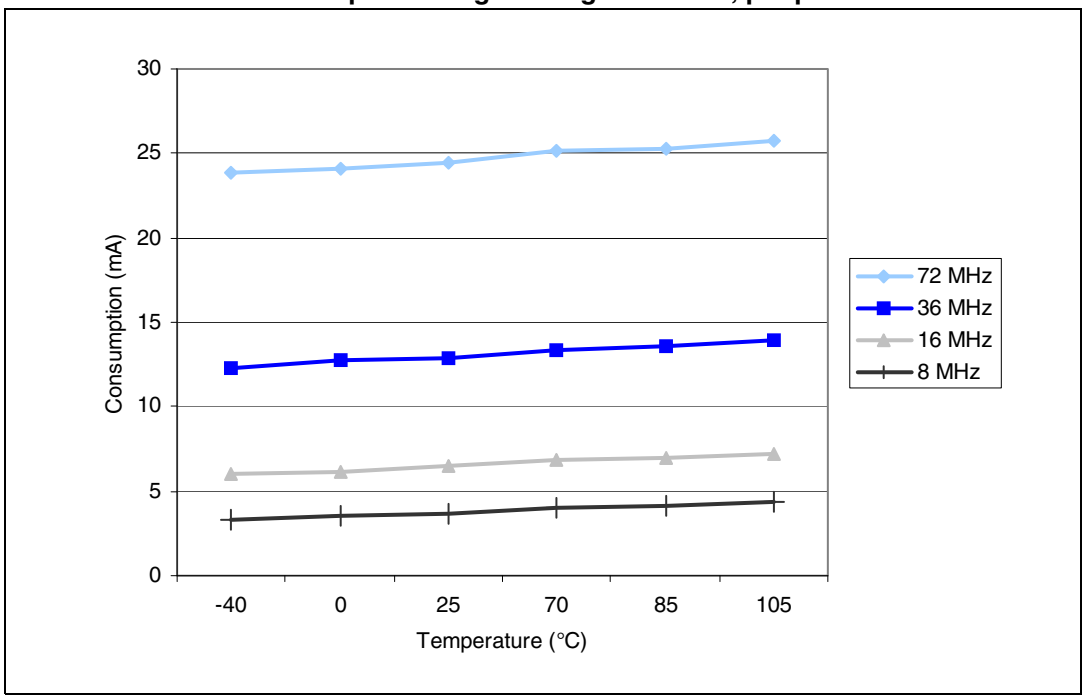


Table 18. Typical current consumption in Sleep mode, code running from Flash or RAM

Symbol	Parameter	Conditions	f_{HCLK}	Typ(1)		Unit
				All peripherals enabled(2)	All peripherals disabled	
I_{DD}	Supply current in Sleep mode	External clock(3)	72 MHz	14.4	5.5	mA
			48 MHz	9.9	3.9	
			36 MHz	7.6	3.1	
			24 MHz	5.3	2.3	
			16 MHz	3.8	1.8	
			8 MHz	2.1	1.2	
			4 MHz	1.6	1.1	
			2 MHz	1.3	1	
			1 MHz	1.11	0.98	
			500 kHz	1.04	0.96	
			125 kHz	0.98	0.95	
		Running on high speed internal RC (HSI), AHB prescaler used to reduce the frequency	64 MHz	12.3	4.4	
			48 MHz	9.3	3.3	
			36 MHz	7	2.5	
			24 MHz	4.8	1.8	
			16 MHz	3.2	1.2	
			8 MHz	1.6	0.6	
			4 MHz	1	0.5	
			2 MHz	0.72	0.47	
			1 MHz	0.56	0.44	
			500 kHz	0.49	0.42	
			125 kHz	0.43	0.41	

1. Typical values are measures at T_A = 25 °C, V_{DD} = 3.3 V.
2. Add an additional power consumption of 0.8 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is on (ADON bit is set in the ADC_CR2 register).
3. External clock is 8 MHz and PLL is on when f_{HCLK} > 8 MHz.

On-chip peripheral current consumption

The current consumption of the on-chip peripherals is given in *Table 19*. The MCU is placed under the following conditions:

- all I/O pins are in input mode with a static value at V_{DD} or V_{SS} (no load)
- all peripherals are disabled unless otherwise mentioned
- the given value is calculated by measuring the current consumption
  - with all peripherals clocked off
  - with only one peripheral clocked on
- ambient operating temperature and V_{DD} supply voltage conditions summarized in *Table 6*

Table 19. Peripheral current consumption(1)

Peripheral		Typical consumption at 25 °C	Unit
APB1	TIM2	1.2	mA
	TIM3	1.2	
	TIM4	0.9	
	SPI2	0.2	
	USART2	0.35	
	USART3	0.35	
	I2C1	0.39	
	I2C2	0.39	
	USB	0.65	
	CAN	0.72	
APB2	GPIO A	0.47	mA
	GPIO B	0.47	
	GPIO C	0.47	
	GPIO D	0.47	
	GPIO E	0.47	
	ADC1(2)	1.81	
	ADC2	1.78	
	TIM1	1.6	
	SPI1	0.43	
	USART1	0.85	

1. f_{HCLK} = 72 MHz, $f_{APB1} = f_{HCLK}/2$, $f_{APB2} = f_{HCLK}$, default prescaler value for each peripheral.
2. Specific conditions for ADC: f_{HCLK} = 56 MHz, $f_{APB1} = f_{HCLK}/2$, $f_{APB2} = f_{HCLK}$, $f_{ADCCLK} = f_{APB2/4}$, ADON bit in the ADC_CR2 register is set to 1.

Table 26. Low-power mode wakeup timings

Symbol	Parameter	Conditions	Typ	Unit
$t_{WUSLEEP}$(1)	Wakeup from Sleep mode	Wakeup on HSI RC clock	1.8	µs
t_{WUSTOP}(1)	Wakeup from Stop mode (regulator in run mode)	HSI RC wakeup time = 2 µs	3.6	µs
	Wakeup from Stop mode (regulator in low power mode)	HSI RC wakeup time = 2 µs, Regulator wakeup from LP mode time = 5 µs	5.4	
$t_{WUSTDBY}$(1)	Wakeup from Standby mode	HSI RC wakeup time = 2 µs, Regulator wakeup from power down time = 38 µs	50	µs

1. The wakeup times are measured from the wakeup event to the point in which the user application code reads the first instruction.

5.3.8 PLL characteristics

The parameters given in *Table 27* are derived from tests performed under ambient temperature and V_{DD} supply voltage conditions summarized in *Table 9*.

Table 27. PLL characteristics

Symbol	Parameter	Test conditions	Value			Unit
			Min(1)	Typ	Max(1)	
f_{PLL_IN}	PLL input clock(2)		1	8.0	25	MHz
	PLL input clock duty cycle		40		60	%
f_{PLL_OUT}	PLL multiplier output clock		16		72	MHz
t_{LOCK}	PLL lock time				200	µs

1. Based on characterization, not tested in production.
2. Take care of using the appropriate multiplier factors so as to have PLL input clock values compatible with the range defined by f_{PLL_OUT}.

5.3.9 Memory characteristics

Flash memory

The characteristics are given at T_A = –40 to 105 °C unless otherwise specified.

Table 28. Flash memory characteristics

Symbol	Parameter	Conditions	Min(1)	Typ	Max(1)	Unit
t_{prog}	16-bit programming time	T_A = –40 to +105 °C	40	52.5	70	µs
t_{ERASE}	Page (1 KB) erase time	T_A = –40 to +105 °C	20		40	ms
t_{ME}	Mass erase time	T_A = –40 to +105 °C	20		40	ms

5.3.15 Communications interfaces

I²C interface characteristics

Unless otherwise specified, the parameters given in *Table 39* are derived from tests performed under the ambient temperature, f_{PCLK1} frequency and V_{DD} supply voltage conditions summarized in *Table 9*.

The STM32F103xx performance line I²C interface meets the requirements of the standard I²C communication protocol with the following restrictions: the I/O pins SDA and SCL are mapped to are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V_{DD} is disabled, but is still present.

The I²C characteristics are described in *Table 39*. Refer also to *Section 5.3.12: I/O port characteristics* for more details on the input/output alternate function characteristics (SDA and SCL).

Table 39. I²C characteristics

Symbol	Parameter	Standard mode I²C(1)		Fast mode I²C(1)(2)		Unit
		Min	Max	Min	Max	
$t_{w(SCLL)}$	SCL clock low time	4.7		1.3		µs
$t_{w(SCLH)}$	SCL clock high time	4.0		0.6		
$t_{su(SDA)}$	SDA setup time	250		100		ns
$t_{h(SDA)}$	SDA data hold time	0(3)		0(4)	900(3)	
$t_{r(SDA)}$ $t_{r(SCL)}$	SDA and SCL rise time		1000	20 + 0.1C_b	300	
$t_{f(SDA)}$ $t_{f(SCL)}$	SDA and SCL fall time		300		300	
$t_{h(STA)}$	Start condition hold time	4.0		0.6		µs
$t_{su(STA)}$	Repeated Start condition setup time	4.7		0.6		
$t_{su(STO)}$	Stop condition setup time	4.0		0.6		µs
$t_{w(STO:STA)}$	Stop to Start condition time (bus free)	4.7		1.3		µs
C_b	Capacitive load for each bus line		400		400	pF

1. Guaranteed by design, not tested in production.
2. f_{PCLK1} must be higher than 2 MHz to achieve the maximum standard mode I²C frequency. It must be higher than 4 MHz to achieve the maximum fast mode I²C frequency.
3. The maximum hold time of the Start condition has only to be met if the interface does not stretch the low period of SCL signal.
4. The device must internally provide a hold time of at least 300ns for the SDA signal in order to bridge the undefined region of the falling edge of SCL.

SPI interface characteristics

Unless otherwise specified, the parameters given in *Table 41* are derived from tests performed under the ambient temperature, f_{PCLKx} frequency and V_{DD} supply voltage conditions summarized in *Table 9*.

Refer to *Section 5.3.12: I/O port characteristics* for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO).

Table 41. SPI characteristics(1)

Symbol	Parameter	Conditions	Min	Max	Unit
f_{SCK} $1/t_{c(SCK)}$	SPI clock frequency	Master mode	0	18	MHz
		Slave mode	0	18	
$t_{r(SCK)}$ $t_{f(SCK)}$	SPI clock rise and fall time	Capacitive load: C = 30 pF		8	ns
$t_{su(NSS)}$(2)	NSS setup time	Slave mode	4 t_{PCLK}		
$t_{h(NSS)}$(2)	NSS hold time	Slave mode	73		
$t_{w(SCKH)}$(2) $t_{w(SCKL)}$(2)	SCK high and low time	Master mode, f_{PCLK} = 36 MHz, presc = 4	50	60	
$t_{su(MI)}$ (2)	Data input setup time Master mode	SPI1	1		
		SPI2	5		
$t_{su(SI)}$(2)	Data input setup time Slave mode		1		
$t_{h(MI)}$ (2)	Data input hold time Master mode	SPI1	1		
		SPI2	5		
$t_{h(SI)}$(2)	Data input hold time Slave mode		3		
$t_{a(SO)}$(2)(3)	Data output access time	Slave mode, f_{PCLK} = 36 MHz, presc = 4	0	55	
		Slave mode, f_{PCLK} = 24 MHz	0	4 t_{PCLK}	
$t_{dis(SO)}$(2)(4)	Data output disable time	Slave mode	10		
$t_{v(SO)}$ (2)(1)	Data output valid time	Slave mode (after enable edge)		25	
$t_{v(MO)}$(2)(1)	Data output valid time	Master mode (after enable edge)		3	
$t_{h(SO)}$(2)	Data output hold time	Slave mode (after enable edge)	25		
$t_{h(MO)}$(2)		Master mode (after enable edge)	4		

1. Remapped SPI1 characteristics to be determined.
2. Based on characterization, not tested in production.
3. Min time is for the minimum time to drive the output and the max time is for the maximum time to validate the data.
4. Min time is for the minimum time to invalidate the output and the max time is for the maximum time to put the data in Hi-Z

5.3.17 12-bit ADC characteristics

Unless otherwise specified, the parameters given in *Table 45* are derived from tests performed under the ambient temperature, f_{PCLK2} frequency and V_{DDA} supply voltage conditions summarized in *Table 9*.

Note: It is recommended to perform a calibration after each power-up.

Table 45. ADC characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DDA}	Power supply		2.4		3.6	V
V_{REF+}	Positive reference voltage		2.4		V_{DDA}	V
I_{VREF}	Current on the V_{REF} input pin			160(1)	220(1)	µA
f_{ADC}	ADC clock frequency		0.6		14	MHz
f_S(2)	Sampling rate		0.05		1	MHz
f_{TRIG}(2)	External trigger frequency	f_{ADC} = 14 MHz			823	kHz
					17	$1/f_{ADC}$
V_{AIN}(3)	Conversion voltage range		0 (V_{SSA} or V_{REF-} tied to ground)		V_{REF+}	V
R_{AIN}(2)	External input impedance		See *Equation 1* and *Table 46*			kΩ
R_{ADC}(2)	Sampling switch resistance				1	kΩ
C_{ADC}(2)	Internal sample and hold capacitor				12	pF
t_{CAL}(2)	Calibration time	f_{ADC} = 14 MHz	5.9			µs
			83			$1/f_{ADC}$
t_{lat}(2)	Injection trigger conversion latency	f_{ADC} = 14 MHz			0.214	µs
					3(4)	$1/f_{ADC}$
t_{latr}(2)	Regular trigger conversion latency	f_{ADC} = 14 MHz			0.143	µs
					2(4)	$1/f_{ADC}$
t_S(2)	Sampling time	f_{ADC} = 14 MHz	0.107		17.1	µs
			1.5		239.5	$1/f_{ADC}$
t_{STAB}(2)	Power-up time		0	0	1	µs
t_{CONV}(2)	Total conversion time (including sampling time)	f_{ADC} = 14 MHz	1		18	µs
			14 to 252 (t_S for sampling +12.5 for successive approximation)			$1/f_{ADC}$

1. Based on characterization, not tested in production.
2. Guaranteed by design, not tested in production.
3. In devices delivered in VFQFPN and LQFP packages, V_{REF+} is internally connected to V_{DDA} and V_{REF-} is internally connected to V_{SSA}. Devices that come in the TFBGA64 package have a V_{REF+} pin but no V_{REF-} pin (V_{REF-} is internally connected to V_{SSA}), see *Table 5* and *Figure 6*.
4. For external triggers, a delay of $1/f_{PCLK2}$ must be added to the latency specified in *Table 45*.

Table 48. ADC accuracy(1) (2) (3)

Symbol	Parameter	Test conditions	Typ	Max(4)	Unit
ET	Total unadjusted error	f_{PCLK2} = 56 MHz, f_{ADC} = 14 MHz, R_{AIN} < 10 kΩ, V_{DDA} = 2.4 V to 3.6 V Measurements made after ADC calibration	±2	±5	LSB
EO	Offset error		±1.5	±2.5	
EG	Gain error		±1.5	±3	
ED	Differential linearity error		±1	±2	
EL	Integral linearity error		±1.5	±3	

1. ADC DC accuracy values are measured after internal calibration.
2. Better performance could be achieved in restricted V_{DD}, frequency and temperature ranges.
3. ADC Accuracy vs. Negative Injection Current: Injecting negative current on any of the standard (non-robust) analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to standard analog pins which may potentially inject negative current.
Any positive injection current within the limits specified for $I_{INJ(PIN)}$ and $\Sigma I_{INJ(PIN)}$ in *Section 5.3.12* does not affect the ADC accuracy.
4. Based on characterization, not tested in production.

Figure 30. ADC accuracy characteristics

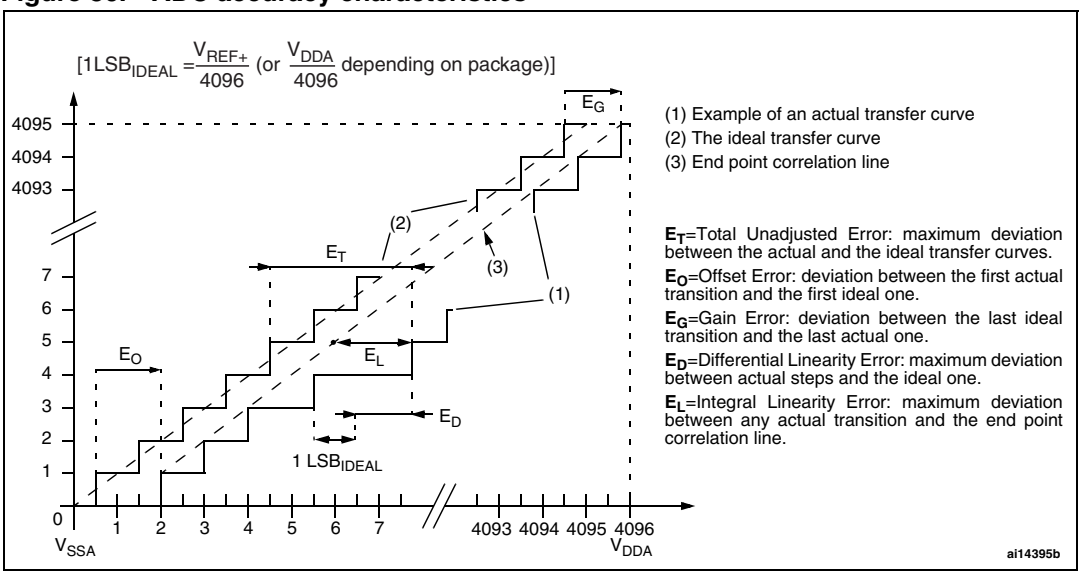
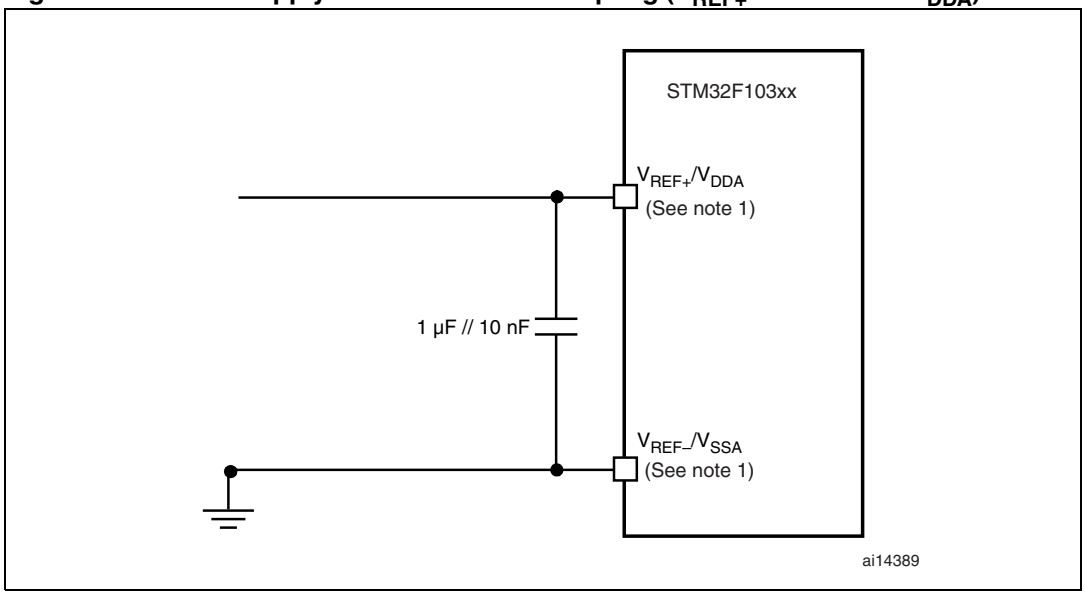


Figure 33. Power supply and reference decoupling (V_{REF+} connected to V_{DDA})



1. V_{REF+} and V_{REF-} inputs are available only on 100-pin packages.

5.3.18 Temperature sensor characteristics

Table 49. TS characteristics

Symbol	Parameter	Min	Typ	Max	Unit
T_L[1]	V_{SENSE} linearity with temperature		±1	±2	°C
Avg_Slope[1]	Average slope	4.0	4.3	4.6	mV/°C
V_{25}[1]	Voltage at 25 °C	1.34	1.43	1.52	V
t_{START}[2]	Startup time	4		10	µs
T_{S_temp}[3][2]	ADC sampling time when reading the temperature			17.1	µs

1. Based on characterization, not tested in production.
2. Guaranteed by design, not tested in production.
3. Shortest sampling time can be determined in the application by multiple iterations.

Figure 34. VFQFPN36 6 x 6 mm, 0.5 mm pitch, package outline(1)

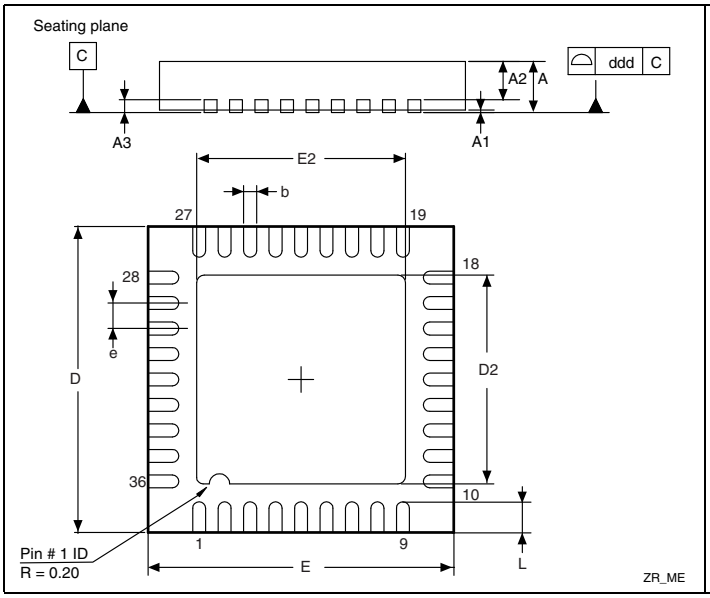
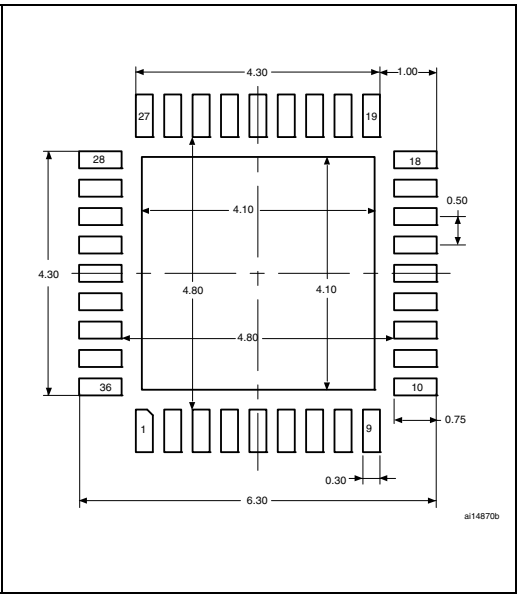


Figure 35. Recommended footprint (dimensions in mm)(1)(2)(3)



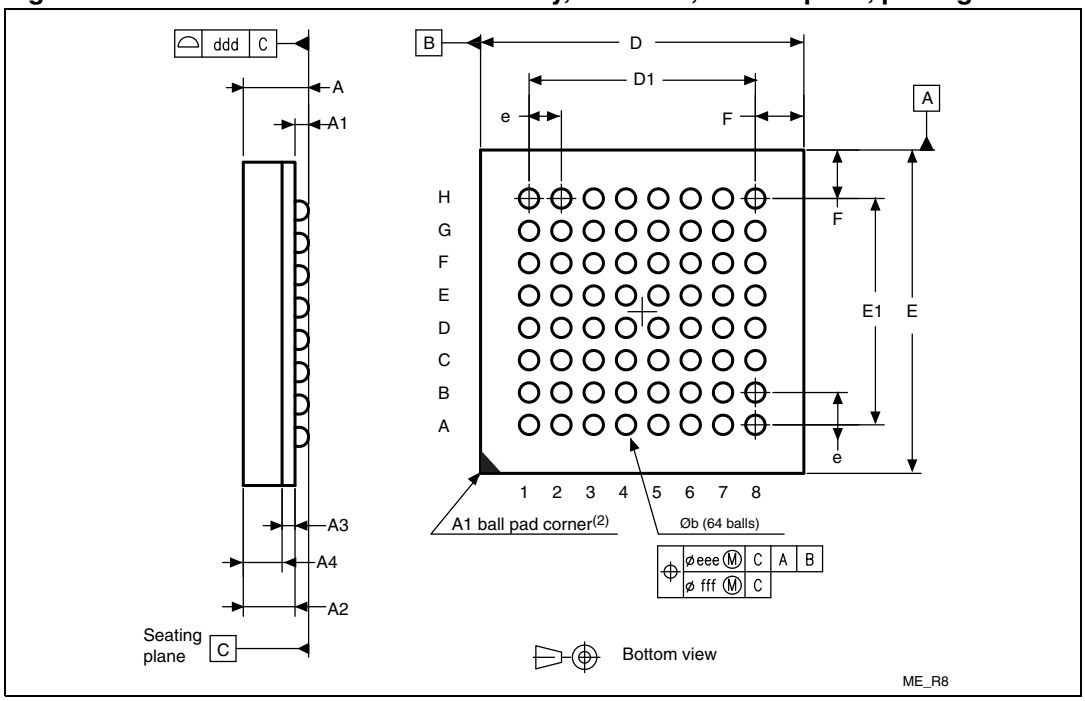
1. Drawing is not to scale.
2. The back-side pad is not internally connected to the V_{SS} or V_{DD} power pads.
3. There is an exposed die pad on the underside of the VFQFPN package. It should be soldered to the PCB. All leads should also be soldered to the PCB.

Table 50. VFQFPN36 6 x 6 mm, 0.5 mm pitch, package mechanical data

Symbol	millimeters			inches(1)		
	Min	Typ	Max	Min	Typ	Max
A	0.800	0.900	1.000	0.0315	0.0354	0.0394
A1		0.020	0.050		0.0008	0.0020
A2		0.650	1.000		0.0256	0.0394
A3		0.250			0.0098	
b	0.180	0.230	0.300	0.0071	0.0091	0.0118
D	5.875	6.000	6.125	0.2313	0.2362	0.2411
D2	1.750	3.700	4.250	0.0689	0.1457	0.1673
E	5.875	6.000	6.125	0.2313	0.2362	0.2411
E2	1.750	3.700	4.250	0.0689	0.1457	0.1673
e	0.450	0.500	0.550	0.0177	0.0197	0.0217
L	0.350	0.550	0.750	0.0138	0.0217	0.0295
ddd		0.080			0.0031	

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 42. TFBGA64 - 8 x 8 active ball array, 5 x 5 mm, 0.5 mm pitch, package outline



1. Drawing is not to scale.

Table 54. TFBGA64 - 8 x 8 active ball array, 5 x 5 mm, 0.5 mm pitch, package mechanical data

Symbol	millimeters			inches(1)		
	Typ	Min	Max	Typ	Min	Max
A			1.200			0.0472
A1		0.150			0.0059	
A2	0.785			0.0309		
A3	0.200			0.0079		
A4			0.600			0.0236
b	0.300	0.250	0.350	0.0118	0.0098	0.0138
D	5.000	4.850	5.150	0.1969	0.1909	0.2028
D1	3.500			0.1378		
E	5.000	4.850	5.150	0.1969	0.1909	0.2028
E1	3.500			0.1378		
e	0.500			0.0197		
F	0.750			0.0295		
ddd	0.080			0.0031		
eee	0.150			0.0059		
fff	0.050			0.0020		

1. Values in inches are converted from mm and rounded to 4 decimal digits.

Figure 44. LQFP48, 48-pin low-profile quad flat package outline(1)

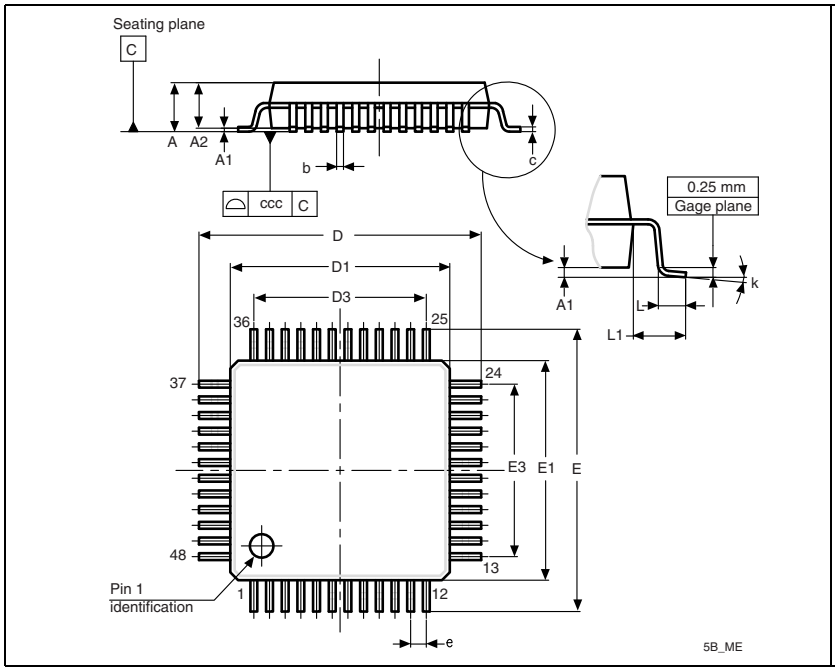
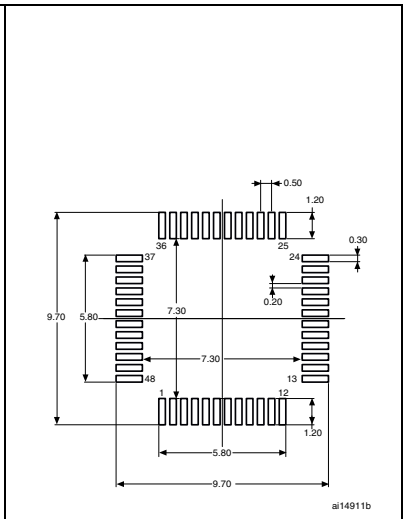


Figure 45. Recommended footprint(1)(2)



1. Drawing is not to scale.
2. Dimensions are in millimeters.

Table 55. LQFP48, 48-pin low-profile quad flat package mechanical data

Symbol	millimeters			inches(1)		
	Typ	Min	Max	Typ	Min	Max
A			1.600			0.0630
A1		0.050	0.150		0.0020	0.0059
A2	1.400	1.350	1.450	0.0551	0.0531	0.0571
b	0.220	0.170	0.270	0.0087	0.0067	0.0106
c		0.090	0.200		0.0035	0.0079
D	9.000	8.800	9.200	0.3543	0.3465	0.3622
D1	7.000	6.800	7.200	0.2756	0.2677	0.2835
D3	5.500			0.2165		
E	9.000	8.800	9.200	0.3543	0.3465	0.3622
E1	7.000	6.800	7.200	0.2756	0.2677	0.2835
E3	5.500			0.2165		
e	0.500			0.0197		
L	0.600	0.450	0.750	0.0236	0.0177	0.0295
L1	1.000			0.0394		
k	3.5°	0°	7°	3.5°	0°	7°
ccc		0.080			0.0031	

1. Values in inches are converted from mm and rounded to 4 decimal digits.

7 Ordering information scheme

Table 57. Ordering information scheme

Example: STM32 F 103 C 8 T 7 xxx

Device family

STM32 = ARM-based 32-bit microcontroller

Product type

F = general-purpose

Device subfamily

103 = performance line

Pin count

T = 36 pins
C = 48 pins
R = 64 pins
V = 100 pins

Flash memory size(1)

8 = 64 Kbytes of Flash memory
B = 128 Kbytes of Flash memory

Package

H = BGA
T = LQFP
U = VFQFPN

Temperature range

6 = Industrial temperature range, –40 to 85 °C.
7 = Industrial temperature range, –40 to 105 °C.

Options

xxx = programmed parts
TR = tape and real

1. Although STM32F103x6 devices are not described in this datasheet, orderable part numbers that do not show the A internal code after temperature range code 6 or 7 should be referred to this datasheet for the electrical characteristics. The low-density datasheet only covers STM32F103x6 devices that feature the A code.

For a list of available options (speed, package, etc.) or for further information on any aspect of this device, please contact your nearest ST sales office.